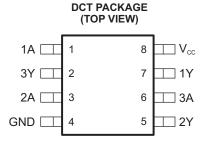


FEATURES

- Available in the Texas Instruments NanoFree[™] Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V .
- Max t_{nd} of 5.4 ns at 3.3 V •
- Low Power Consumption, 10-µA Max Icc
- ±24-mA Output Drive at 3.3 V ٠
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^{\circ}C$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at V_{CC} = 3.3 V, T_A = 25°C



- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

I		PACKAGE P VIEW)	E		PACK	
1A 🗆	1	8	⊥ V _{cc}		O4 50	2Y
3Y 🖂	2	7	∏ 1Y	2A	O36O	ЗA
2A ∏	3	6	3A	3Y	0270	1Y
	3	0		1A	0180	V _{CC}
GND 🗌	4	5	<u>∏</u> 2Y			

See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

This triple Schmitt-trigger buffer is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC3G17 contains three buffers and performs the Boolean function Y = A. The device functions as three independent buffers but, because of Schmitt action, it may have different input threshold levels for positive-going (V_{T+}) and negative-going (V_{T-}) signals.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾		
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC3G17YZPR	C7_		
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74LVC3G17DCTR	C17		
	VSSOP – DCU	Reel of 3000	SN74LVC3G17DCUR	C17_		

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

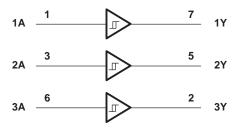


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FUNCTION TABLE (EACH INVERTER)

INPUT A	OUTPUT Y
Н	Н
L	L

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the h	nigh-impedance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current V _O < 0			-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCU package		227	°C/W
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.
 (4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT		
V_{CC}	Supply voltage	Operating	1.65	5.5	V		
VI	Input voltage		0	5.5	V		
Vo	Output voltage		0	V _{CC}	V		
		V _{CC} = 1.65 V		-4			
		V _{CC} = 2.3 V		-8			
I _{OH}	High-level output current	$V_{CC} = 3 V$		-16	mA		
		$v_{\rm CC} = 3 v$		-24			
		V _{CC} = 4.5 V		-32			
		V _{CC} = 1.65 V		4			
		V _{CC} = 2.3 V		8			
I _{OL}	Low-level output current	<u> </u>		16	mA		
		V _{CC} = 3 V		24			
		V _{CC} = 4.5 V		32			
T _A	Operating free-air temperature		-40	85	°C		

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN74LVC3G17 **TRIPLE SCHMITT-TRIGGER BUFFER**

SCES470D-AUGUST 2003-REVISED FEBRUARY 2007



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	UNIT
		1.65 V	0.79	1.16	
V _{T+}		2.3 V	1.11	1.56	
Positive-going input threshold		3 V	1.5	1.87	V
voltage		4.5 V	2.16	2.74	
		5.5 V	2.61	3.33	
		1.65 V	0.39	0.62	
V _{T-}		2.3 V	0.58	0.87	
Negative-going input threshold		3 V	0.84	1.14	V
voltage		4.5 V	1.41	1.79	
		5.5 V	1.87	2.29	
		1.65 V	0.37	0.62	
ΔV_T		2.3 V	0.48	0.77	
Hysteresis		3 V	0.56	0.87	V
$V_{T+} - V_{T-}$		4.5 V	0.71	1.04	
		5.5 V	0.71	1.11	
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} – 0.1		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		
V _{OH}	I _{OH} = -16 mA	0.14	2.4		V
	$I_{OH} = -24 \text{ mA}$	3 V	2.3		
	I _{OH} = -32 mA	4.5 V	3.8		
	I _{OL} = 100 μA	1.65 V to 5.5 V		0.1	
	$I_{OL} = 4 \text{ mA}$	1.65 V		0.45	
N/	I _{OL} = 8 mA	2.3 V		0.3	V
V _{OL}	I _{OL} = 16 mA	2.14		0.4	V
	I _{OL} = 24 mA	3 V		0.55	
	I _{OL} = 32 mA	4.5 V		0.55	
I _I	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V		±1	μA
I _{off}	V_{I} or $V_{O} = 5.5 V$	0		±5	μA
I _{CC}	$V_{I} = 5.5 \text{ V or GND}, I_{O} = 0$	1.65 V to 5.5 V		10	μA
ΔI_{CC}	One input at $V_{CC} - 0.6 V$, Other inputs at V_{CC} or GND	3 V to 5.5 V		500	μA
CI	$V_{I} = V_{CC}$ or GND	3.3 V		4	pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25 ^{\circ}C.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 2)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V_{CC} = 2.5 V ± 0.2 V		V_{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
	(INPOT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
	t _{pd}	А	Y	4.3	9.2	2	6.2	1.2	5.4	1	4.1	ns

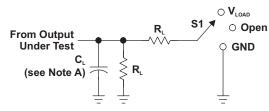
Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	$V_{CC} = 5 V$	UNIT
		TEST CONDITIONS	TYP	TYP	TYP	TYP	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	18	19	19	22	pF



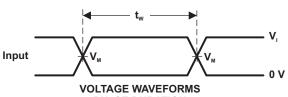
PARAMETER MEASUREMENT INFORMATION

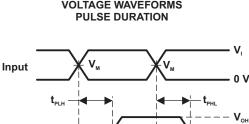


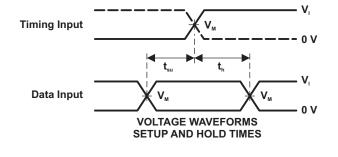
TEST	S1
t _{PLH} /t _{PHL}	Open
t_{PLZ}/t_{PZL}	V_{load}
$t_{_{PHZ}}/t_{_{PZH}}$	GND

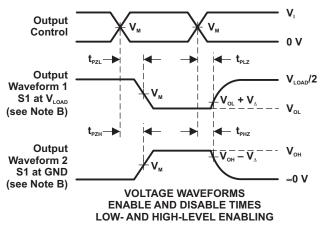
LOAD CIRCUIT

V	IN	PUTS	N	N	•	-	
V _{cc}	V	t,/t,	V _M	VLOAD	C∟	R	V
1.8 V ± 0.15 V	V_{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.15 V
$2.5~V\pm0.2~V$	V_{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.15 V
$3.3 \text{ V} \pm 0.3 \text{ V}$	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 Μ Ω	0.3 V
$5 V \pm 0.5 V$	V_{cc}	≤2.5 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.3 V









NOTES: A. C_{L} includes probe and jig capacitance.

VOLTAGE WAVEFORMS

PROPAGATION DELAY TIMES

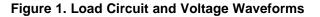
INVERTING AND NONINVERTING OUTPUTS

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.

 \mathbf{V}_{ol}

V,

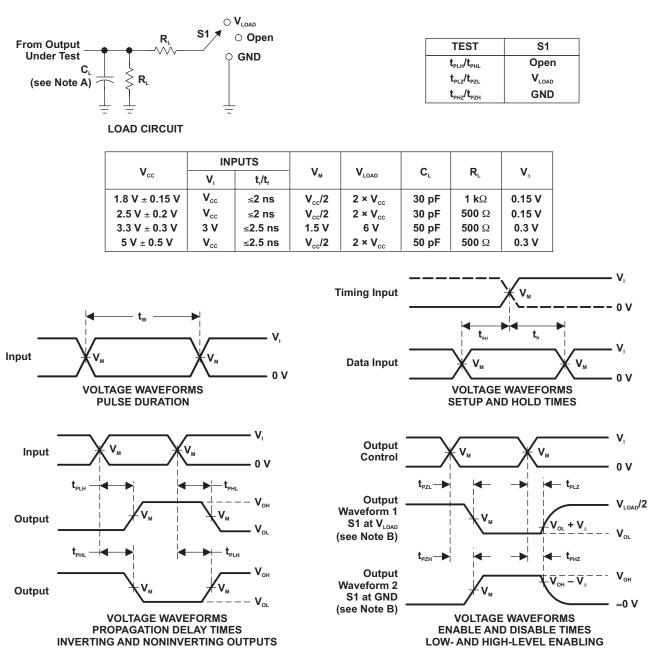
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.



Output

Output

PARAMETER MEASUREMENT INFORMATION



NOTES: A. $C_{\scriptscriptstyle L}$ includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. $t_{\mbox{\tiny PLZ}}$ and $t_{\mbox{\tiny PHZ}}$ are the same as $t_{\mbox{\tiny dis}}.$
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{od} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms



26-Mar-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74LVC3G17DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C17 Z	Samples
SN74LVC3G17DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C17 Z	Samples
SN74LVC3G17DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C17 Z	Samples
SN74LVC3G17DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	(17 ~ C17R) CZ	Samples
SN74LVC3G17DCURE4	ACTIVE	US8	DCU	8		TBD	Call TI	Call TI	-40 to 85		Samples
SN74LVC3G17DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C17R	Samples
SN74LVC3G17YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(C77 ~ C7N)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.



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26-Mar-2013

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	Il dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant	
SN74LVC3G17DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3	
SN74LVC3G17DCURG4	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3	
SN74LVC3G17YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1	

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC3G17DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC3G17DCURG4	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC3G17YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

MECHANICAL DATA

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



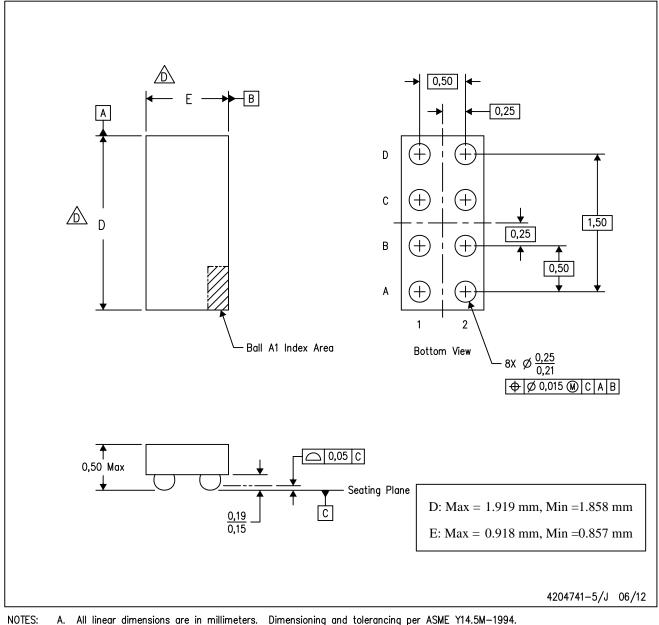


- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α.

- This drawing is subject to change without notice. B.
- NanoFree™ package configuration. Ç.

/ The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative. E. This package is a Pb-free solder ball design. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

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OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com		
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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный) **Факс:** 8 (812) 320-02-42 **Электронная почта:** <u>org@eplast1.ru</u> **Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.